

/ Descriptions

TO-126F PNP Silicon PNP transistor in a TO-126F Plastic Package.

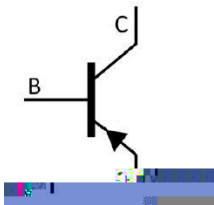
/ Features

High breakdown voltage, low collector saturation voltage, high speed switching.

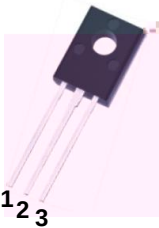
/ Applications

High voltage switching, low power switching regulator, DC-DC converter.

/ Equivalent Circuit



/ Pinning



PIN1 Emitter PIN 2 Collector PIN 3 Base

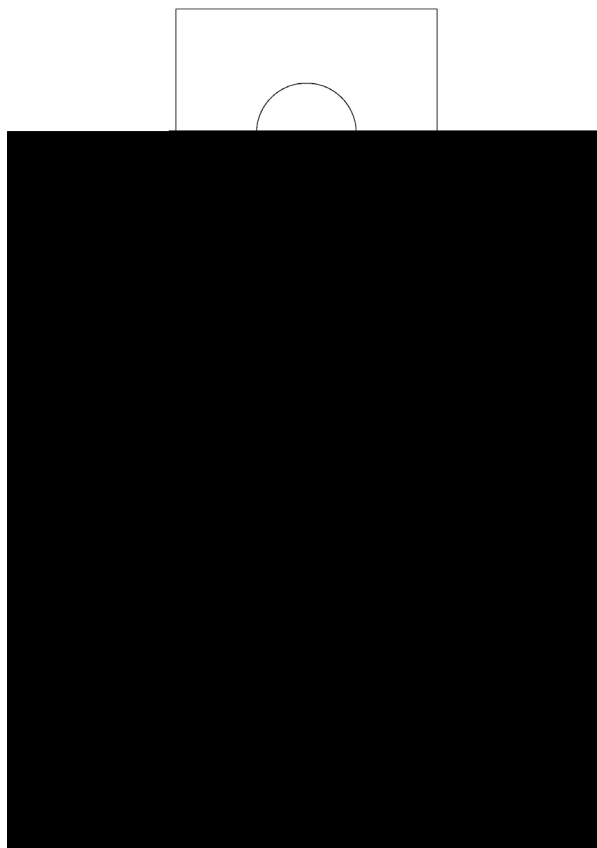
/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	N	R	O	Y
h_{FE} Range	30 60	40 80	60 120	100 200

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-400	V
Collector to Emitter Voltage	V_{CEO}		

KSA1156

/ Marking Instructions



BR

A1156

N

h_{FE}

Note:

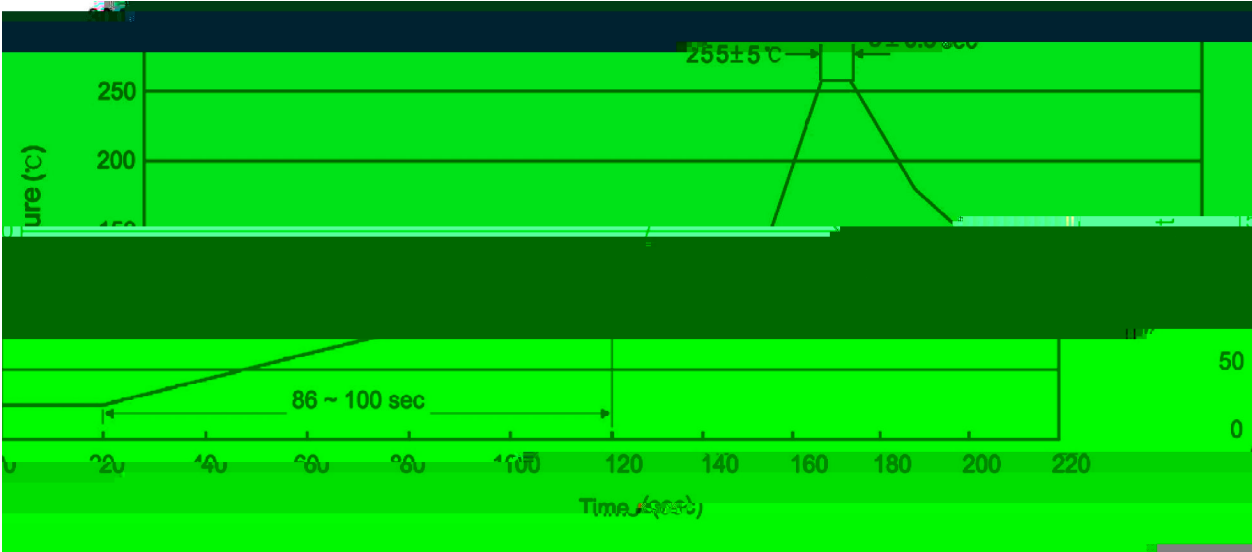
BR: Company Code

A1156: Product Type.

N: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;
- 2

255±5

5±0.5sec;
- 3

2 10 /sec.
- 1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units	Dimension	(unit mm ³)
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